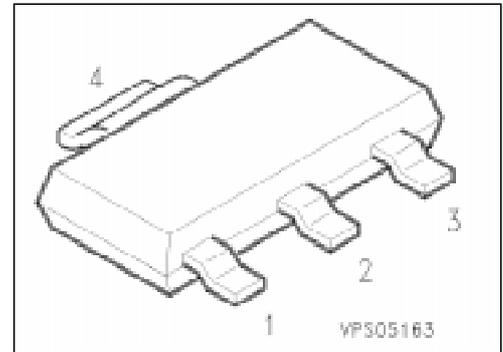


## PNP Silicon AF Transistors

**BCP 51**  
**... BCP 53**

- For AF driver and output stages
- High collector current
- Low collector-emitter saturation voltage
- Complementary types: BCP 54 ... BCP 56 (NPN)



| Type      | Marking   | Ordering Code<br>(tape and reel) | Pin Configuration |   |   |   | Package <sup>1)</sup> |
|-----------|-----------|----------------------------------|-------------------|---|---|---|-----------------------|
|           |           |                                  | 1                 | 2 | 3 | 4 |                       |
| BCP 51    | BCP 51    | Q62702-C2107                     | B                 | C | E | C | SOT-223               |
| BCP 51-10 | BCP 51-10 | Q62702-C2109                     |                   |   |   |   |                       |
| BCP 51-16 | BCP 51-16 | Q62702-C2110                     |                   |   |   |   |                       |
| BCP 52    | BCP 52    | Q62702-C2146                     |                   |   |   |   |                       |
| BCP 52-10 | BCP 52-10 | Q62702-C2112                     |                   |   |   |   |                       |
| BCP 52-16 | BCP 52-16 | Q62702-C2113                     |                   |   |   |   |                       |
| BCP 53    | BCP 53    | Q62702-C2147                     |                   |   |   |   |                       |
| BCP 53-10 | BCP 53-10 | Q62702-C2115                     |                   |   |   |   |                       |
| BCP 53-16 | BCP 53-16 | Q62702-C2116                     |                   |   |   |   |                       |

<sup>1)</sup> For detailed information see chapter Package Outlines.

## Maximum Ratings

| Parameter  | Symbol    | Values         |        |        | Unit             |
|--|-----------|----------------|--------|--------|------------------|
|  |           | BCP 51         | BCP 52 | BCP 53 |                  |
| Collector-emitter voltage<br>$R_{BE} \leq 1 \text{ k}\Omega$   | $V_{CE0}$ | 45             | 60     | 80     | V                |
|  | $V_{CER}$ | 45             | 60     | 100    |                  |
| Collector-base voltage   | $V_{CB0}$ | 45             | 60     | 100    |                  |
| Emitter-base voltage   | $V_{EB0}$ | 5              |        |        |                  |
| Collector current  | $I_C$     | 1              |        |        | A                |
| Peak collector current   | $I_{CM}$  | 1.5            |        |        |                  |
| Base current   | $I_B$     | 100            |        |        | mA               |
| Peak base current  | $I_{BM}$  | 200            |        |        |                  |
| Total power dissipation, $T_s = 124 \text{ }^\circ\text{C}^1)$ | $P_{tot}$ | 1.5            |        |        | W                |
| Junction temperature   | $T_j$     | 150            |        |        | $^\circ\text{C}$ |
| Storage temperature range                                      | $T_{stg}$ | - 65 ... + 150 |        |        |                  |

## Thermal Resistance

|                                  |                     |           |     |
|----------------------------------|---------------------|-----------|-----|
| Junction - ambient <sup>1)</sup> | $R_{th \text{ JA}}$ | $\leq 72$ | K/W |
| Junction - soldering point       | $R_{th \text{ JS}}$ | $\leq 17$ |     |

<sup>1)</sup> Package mounted on epoxy pcb 40 mm × 40 mm × 1.5 mm/6 cm<sup>2</sup> Cu.

## Electrical Characteristics

at  $T_A = 25\text{ °C}$ , unless otherwise specified.

| Parameter | Symbol | Values |      |      | Unit |
|-----------|--------|--------|------|------|------|
|           |        | min.   | typ. | max. |      |

### DC characteristics

|  |               |     |     |     |               |
|--|---------------|-----|-----|-----|---------------|
| Collector-emitter breakdown voltage<br>$I_C = 10\text{ mA}$ , $I_B = 0$                            | $V_{(BR)CE0}$ | 45  | –   | –   | V             |
| BCP 51   |               |     |     |     |               |
| BCP 52   |               |     |     |     |               |
| Collector-base breakdown voltage<br>$I_C = 100\text{ }\mu\text{A}$ , $I_B = 0$                     | $V_{(BR)CB0}$ | 60  | –   | –   |               |
| BCP 51   |               |     |     |     |               |
| BCP 52   |               |     |     |     |               |
| Emitter-base breakdown voltage<br>$I_E = 10\text{ }\mu\text{A}$ , $I_C = 0$                        | $V_{(BR)EB0}$ | 80  | –   | –   |               |
| Collector-base cutoff current<br>$V_{CB} = 30\text{ V}$ , $I_E = 0$                                | $I_{CB0}$     | –   | –   | 100 | nA            |
| $V_{CB} = 30\text{ V}$ , $I_E = 0$ , $T_A = 150\text{ °C}$   |               | –   | –   | 20  | $\mu\text{A}$ |
| Emitter-base cutoff current<br>$V_{EB} = 5\text{ V}$ , $I_C = 0$                                   | $I_{EB0}$     | –   | –   | 10  | $\mu\text{A}$ |
| DC current gain <sup>1)</sup><br>$I_C = 5\text{ mA}$ , $V_{CE} = 2\text{ V}$                       | $h_{FE}$      | 25  | –   | –   | –             |
| $I_C = 150\text{ mA}$ , $V_{CE} = 2\text{ V}$  |               |     |     |     |               |
| BCP 51/BCP 52/BCP 53   |               | 40  | –   | 250 |               |
| BCP 51/BCP 52/BCP 53-10  |               | 63  | 100 | 160 |               |
| BCP 51/BCP 52/BCP 53-16  |               | 100 | 160 | 250 |               |
| $I_C = 500\text{ mA}$ , $V_{CE} = 2\text{ V}$  |               | 25  | –   | –   |               |
| Collector-emitter saturation voltage <sup>1)</sup><br>$I_C = 500\text{ mA}$ , $I_B = 50\text{ mA}$ | $V_{CEsat}$   | –   | –   | 0.5 | V             |
| Base-emitter voltage <sup>1)</sup><br>$I_C = 500\text{ mA}$ , $V_{CE} = 2\text{ V}$                | $V_{BE}$      | –   | –   | 1   |               |

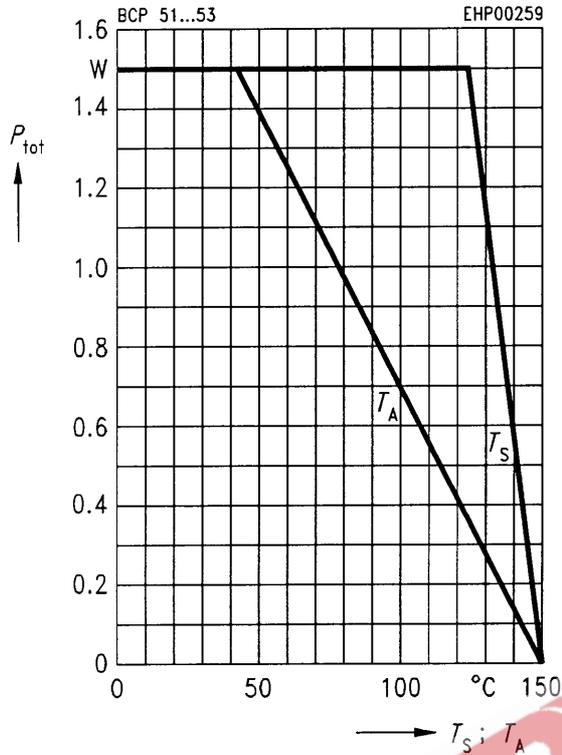
### AC characteristics

|  |       |   |     |   |     |
|--|-------|---|-----|---|-----|
| Transition frequency<br>$I_C = 50\text{ mA}$ , $V_{CE} = 10\text{ V}$ , $f = 100\text{ MHz}$ | $f_T$ | – | 125 | – | MHz |
|--|-------|---|-----|---|-----|

<sup>1)</sup> Pulse test conditions:  $t \leq 300\text{ }\mu\text{s}$ ,  $D = 2\%$ .

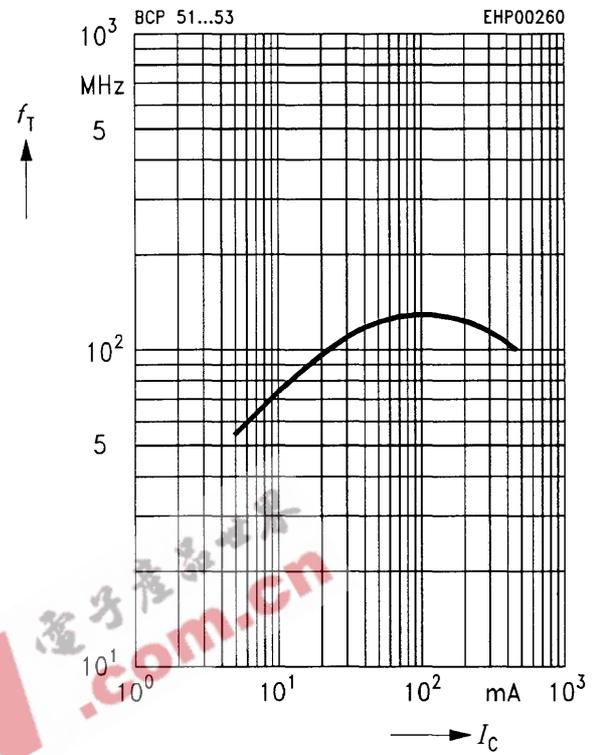
### Total power dissipation $P_{tot} = f(T_A^*; T_S)$

\* Package mounted on epoxy



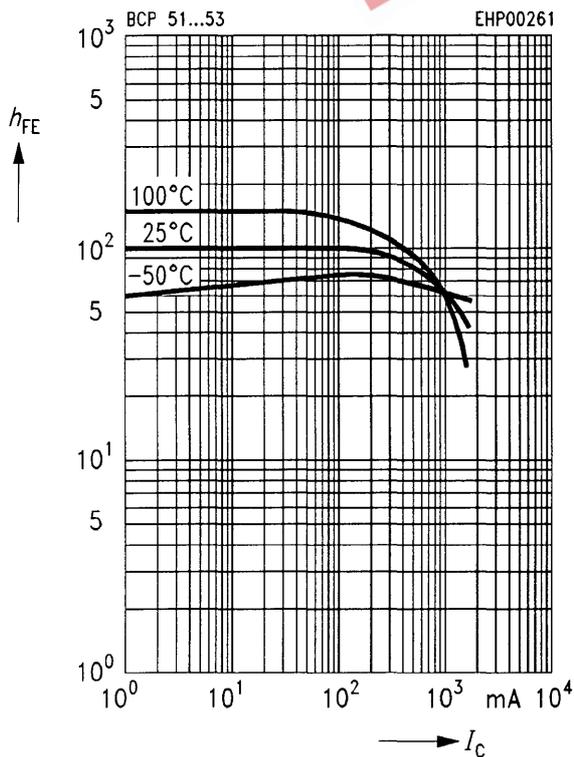
### Transition frequency $f_T = f(I_C)$

$V_{CE} = 10\text{ V}$



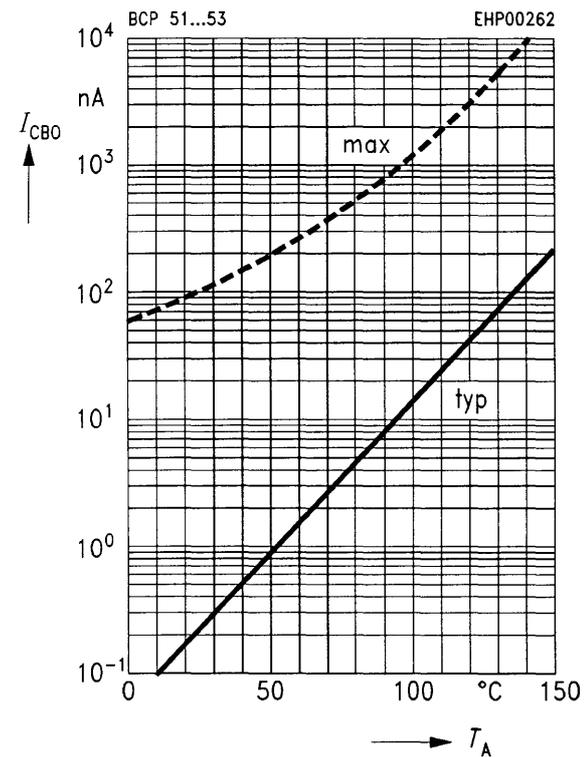
### DC current gain $h_{FE} = f(I_C)$

$V_{CE} = 2\text{ V}$



### Collector cutoff current $I_{CBO} = f(T_A)$

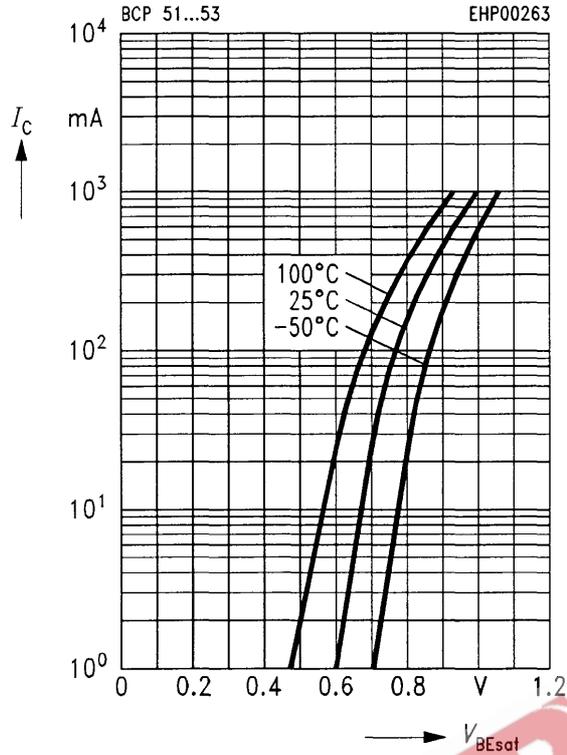
$V_{CB} = 30\text{ V}$



**Base-emitter saturation voltage**

$I_C = f(V_{BEsat})$

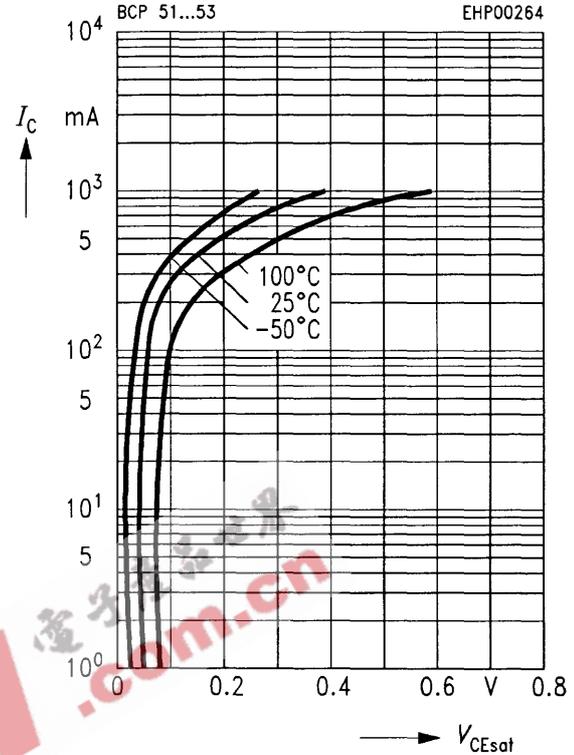
$h_{FE} = 10$



**Collector-emitter saturation voltage**

$I_C = f(V_{CEsat})$

$h_{FE} = 10$



**Permissible pulse load  $P_{tot max}/P_{tot DC} = f(t_p)$**

